

100 W TYPE-C PD3.0 / PPS Charger Solution Evaluation Board User's Manual

EVBUM2818/D

SPECIFICATION

onsemi's Device	Application	Input Voltage	Output Power	Topology	I/O Isolation
NCP1623ASNT1G NCP1343AMDCDBD1R2G NCP4307FASNT1G FUSB15101 FCMT250N65S3 FCMT199N60/FDMS86180 NTTFS4C02NTAG	Smart phone, PAD and NB adapter supporting PD3.0/PPS protocol	90 Vac to 264 Vac	100 W	VSFF PFC Flyback	Isolated (3 kV)

	PD Output Specification	PPS Output Specification
Output Voltage	5 V, 9 V, 12 V, 15 V, 20 V	3 V – 21 V
Nominal Current	5 V / 3 A, 9 V / 3 A, 12 V / 3 A, 15 V / 3 A, 20 V / 5 A	5 A
Max Current	5 V / 3 A, 9 V / 3 A, 12 V / 3 A, 15 V / 3 A, 20 V / 5 A	5 A

Avg. Efficiency	92.3% & 92.9% @ 20 V 3.25 A, 115 & 230 Vac
Ripple	<60 mV
Standby Power	<50 mW @ 5 V & 230 Vac (No cable plug in)
Power Density	1.46 W/cm ³
Protection	Adaptive UVP, OVP, OVP, SCP, OTP
PCBA Size	60 mm x 60 mm x 19 mm

CIRCUIT DESCRIPTION

This evaluation board user's manual describes a 100 W, Type C interface, universal AC input, constant voltage power supply intended for smart phone, PAD and NB adaptor supporting PD3.0/PPS protocol, where isolation from the AC mains is required, and low cost, high efficiency, and low standby power are essential.

The featured power supply is a simple QR flyback topology utilizing **onsemi's** NCP1623 VSFF PFC controller with 2 stage level, NCP1343 Multi-mode HF PWM controller with transient peak excursion power, NCP4307 synchronous rectified controller, **onsemi's** FCMT199N60/FCMT250N65/FDMS86180/NTTFS4C02 MOSFET. This evaluation board user's manual provides the complete circuit schematic details, PCB and BOM for 100 W Type C Interface PD3.0 Power adapter solution which supports PD output (5 V / 3 A, 9 V / 3 A, 12 V / 3 A, 15 V / 3 A, 20 V / 5 A).

This design combined with **onsemi's** FUSB15101 PD3.0/PPS protocol controller to provide PD3.0 and PPS

functions. This design also proposes a dual auxiliary power supply to supply PWM controller, the PWM controller is supplied by high voltage auxiliary voltage at low output voltage and supplied by low voltage auxiliary voltage at high output voltage.

NCP1623 is next generation of NCP1622 PFC controller and compatible with NCP1622, it provides two stage level output and greatly improves the efficiency at low line. NCP1343 has same die as NCP1342, blank IC can be trimmed for NCP1342 or NCP1343, so it should have same reliability as NCP1342. NCP1343 provides a PEM mode with CCM operation and allows to use smaller capacitance for bulk CAP and minimize transformer value for transformer, it will save more size and cost than NCP1342 in a PFC plus PWM applications.

This design also uses NCP4307 synchronous rectified controller which eliminated external Vcc circuit at low output, it is also configured on high side or low side.

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KEY FEATURES & PERFORMANCES

- AC input from 90 V to 264 V
- VSFF CRM PFC with 2 stage output voltage, 250 V at LL and 390 V at HL
- HF CCM/CRM PWM with 2x PEM supports more power transition without PFC working and 68uF PFC capacitor
- High Frequency Operation up to avg. 190 kHz at 264 Vac & full load and easy to be changed to GaN solution
- Quite skip and Flyback DCM operation with frequency foldback at no load & light load
- Output voltage 3.3 V – 21 V
- Max Output power: 100 W
- Support PD3.0, PPS, BC1.2 etc.
- Ripple & Noise: <60 mV
- AVG efficiency: 92% at 115 Vac & 230 Vac
- Full load efficiency: 92.3% & 92.9% at 115 Vac & 230 Vac and 20 V 3.25 A
- Output precise OVP
- Output OCP, SCP
- Open loop protection
- Small size with compact design
- PCBA size: 60 mm x 60 mm x 19 mm

BOARD PHOTOS



Figure 1. Profile of 100 W TYPE-C PD Adapter Solution

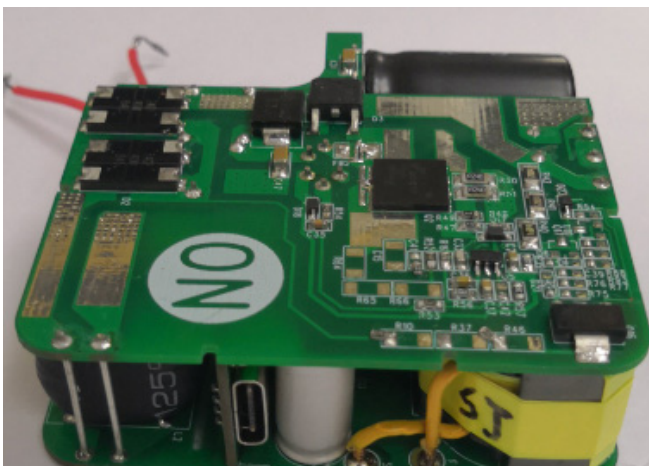


Figure 2. PFC Side View 1 of Demoboard

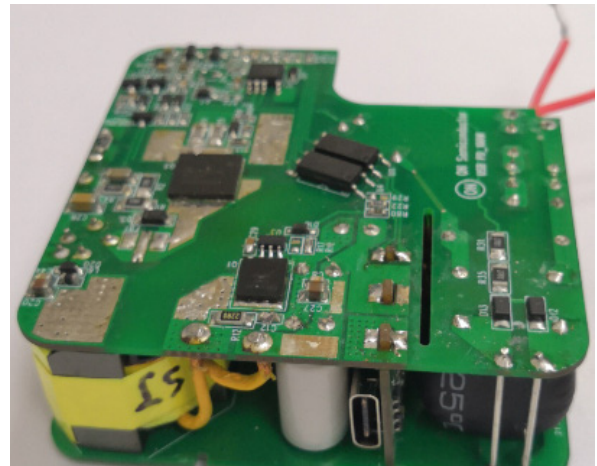


Figure 3. PWM Side View 1 of Demoboard

CIRCUIT SCHEMATIC (PFC)

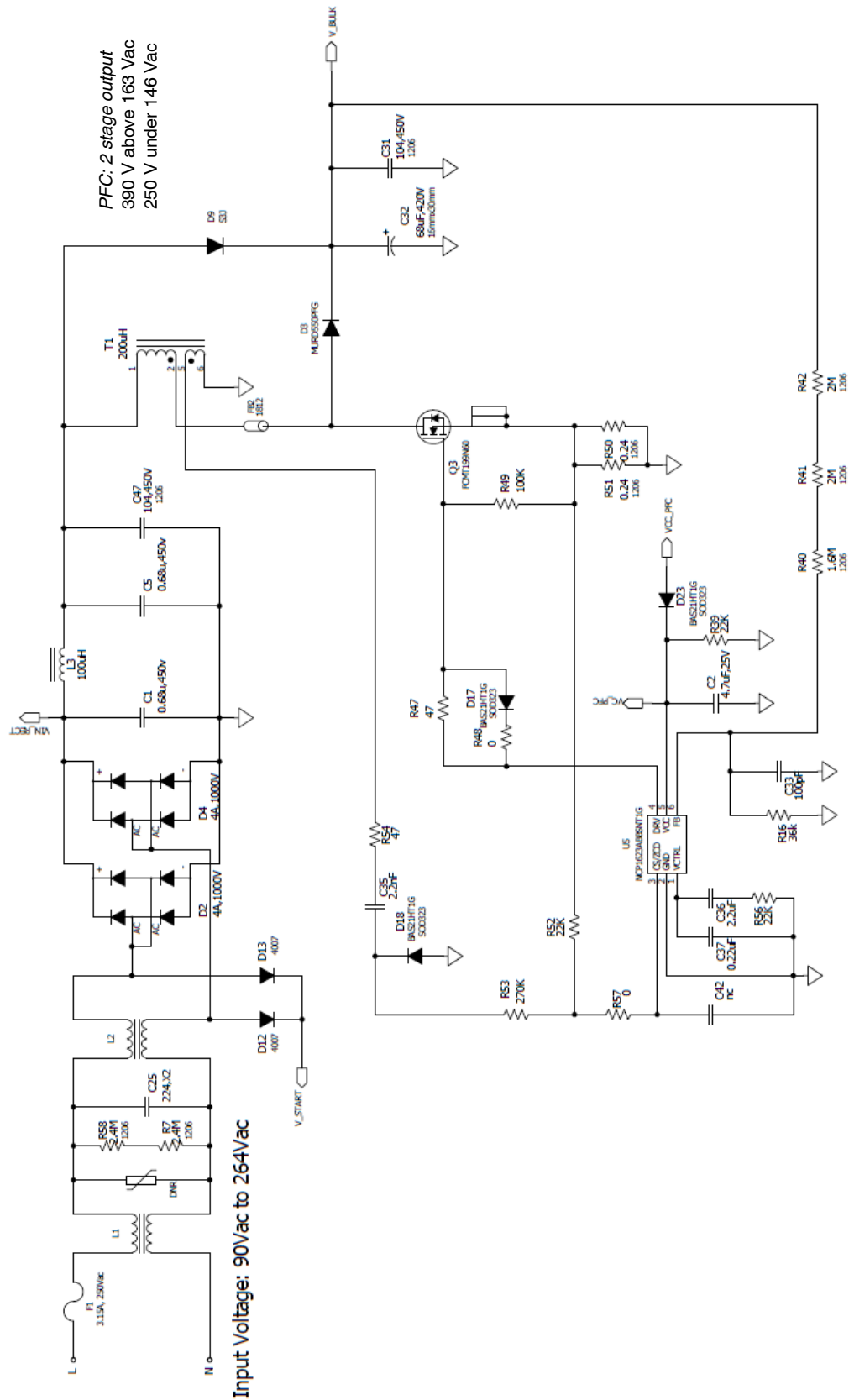


Figure 4. Circuit Schematic (PFC)

CIRCUIT SCHEMATIC (PWM & PROTOCOL)

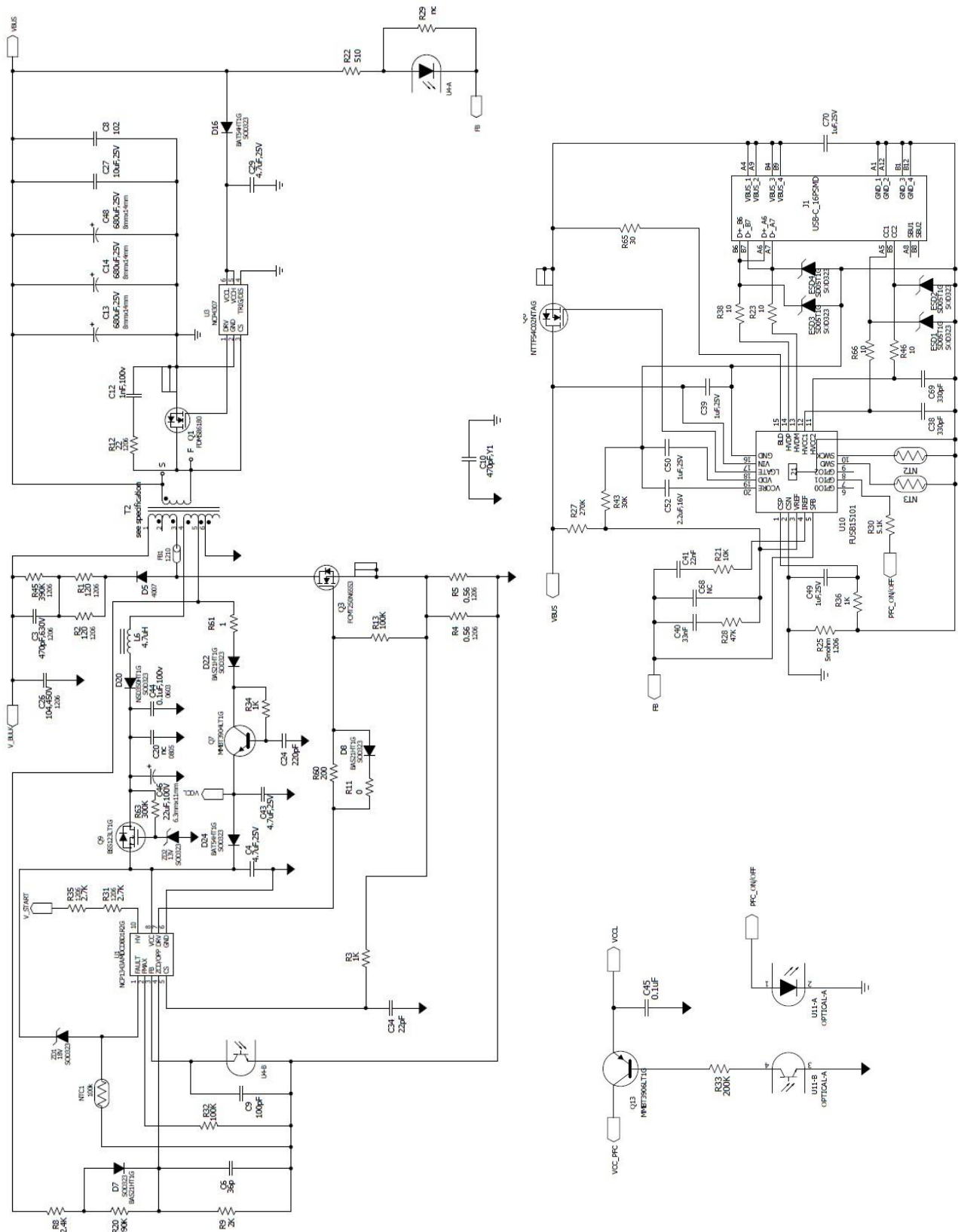


Figure 5. Circuit Schematic (PWM & Protocol)

PCB

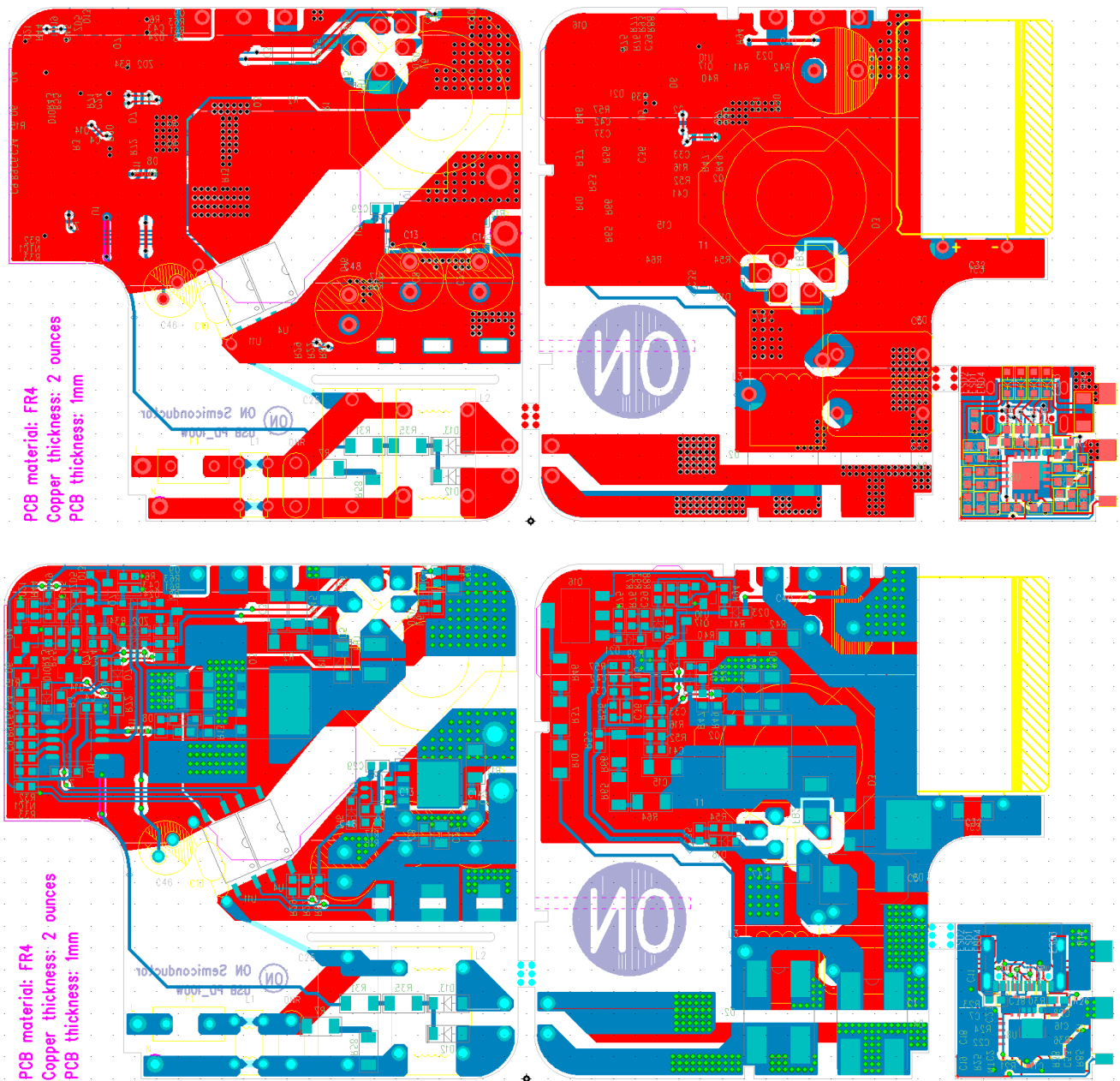


Figure 6. (Top), Top View of PCB

Figure 7. (Bottom), Bottom View of PCB

PFC INDUCTOR SPECIFICATION

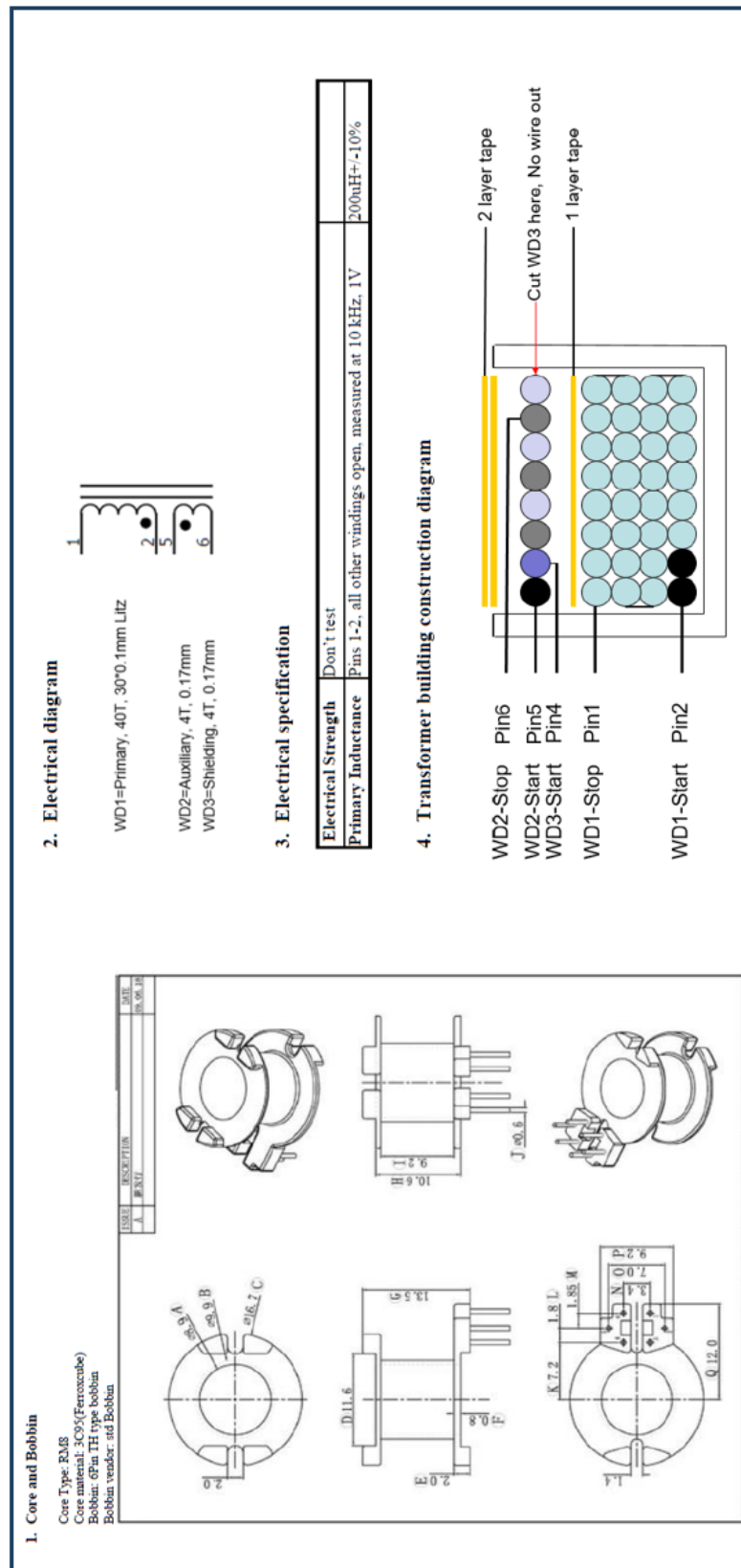


Figure 8. PFC Inductor Specification

TRANSFORMER SPECIFICATION

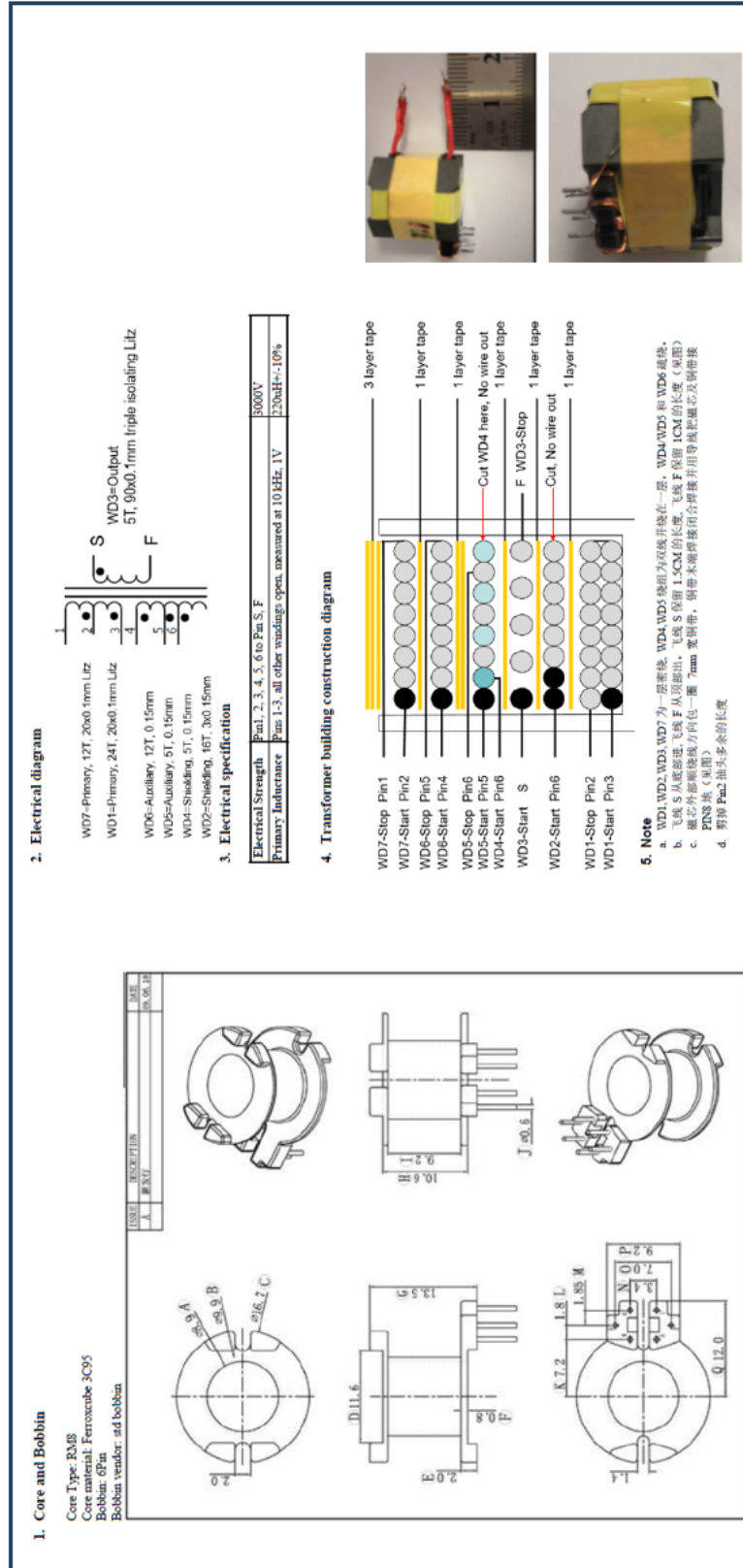


Figure 9. Transformer Specification

STANDBY POWER AT 5 V OUTPUT (CABLE UNPLUG) @ 90 Vac TO 264 Vac INPUT

(Test condition: all efficiency is tested at board end)

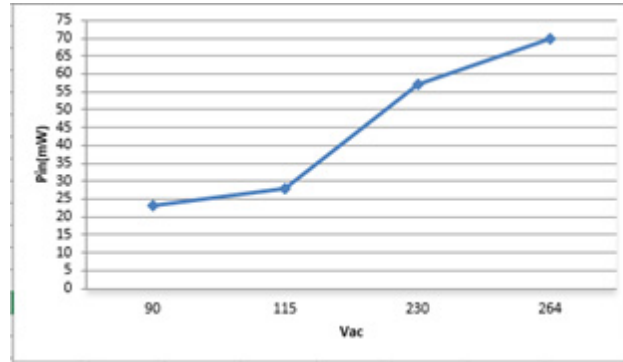


Figure 10.

COC V5 TIER2 SPECIFICATION AND AVERAGE/LIGHT LOAD EFFICIENCY

(Test condition: all efficiency is tested at board end)

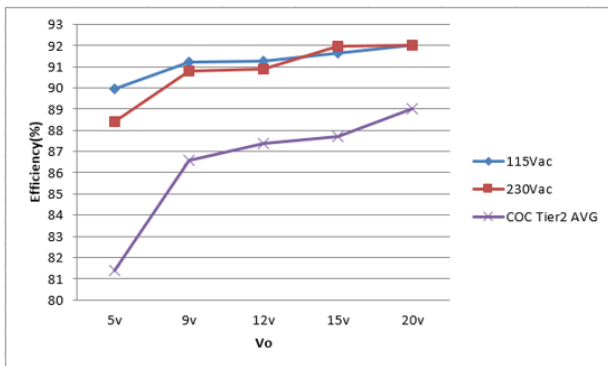


Figure 11. Avg Efficiency vs. COC V5 Tier2

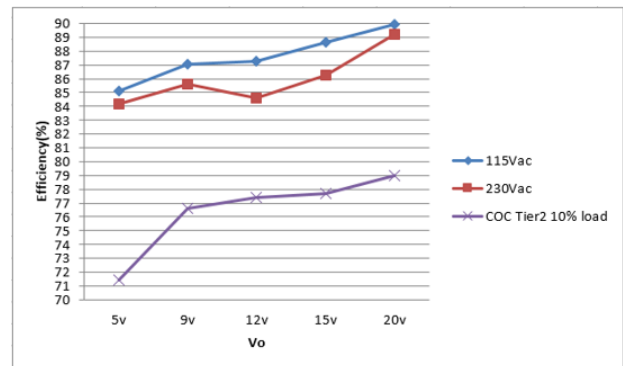


Figure 12. 10% Efficiency vs. COC V5 Tier2

EFFICIENCY VS. OUTPUT LOAD CURVES

(Test condition: all efficiency is tested at board end)

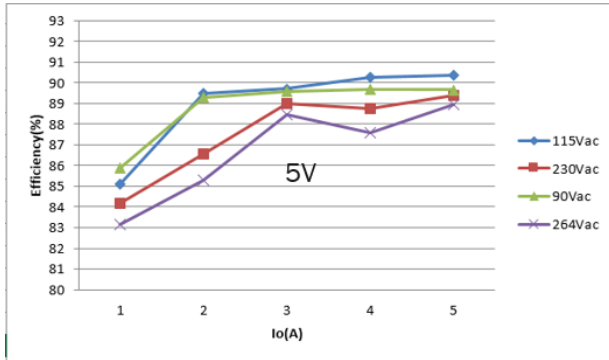


Figure 13. PD_5V Output

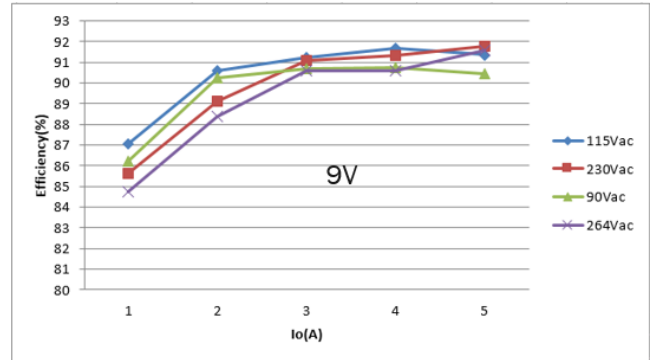


Figure 14. PD_9V Output

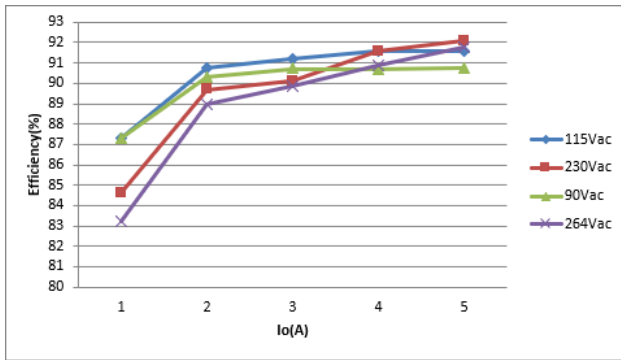


Figure 15. PD_12V Output

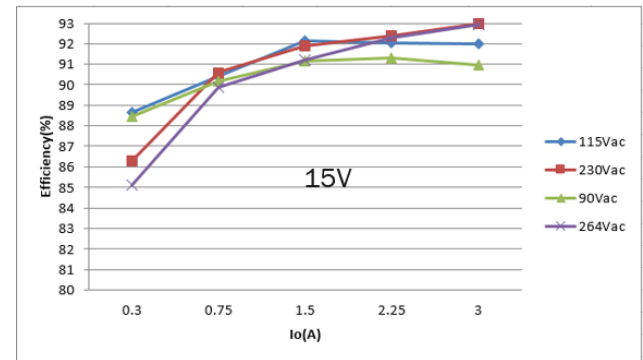


Figure 16. PD_15V Output

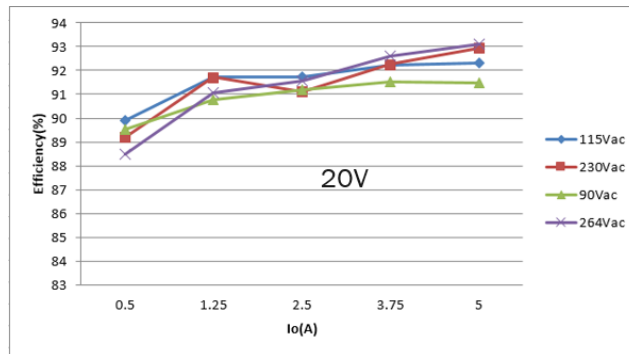


Figure 17. PD_20V Output

PFC VALLEY SWITCHING

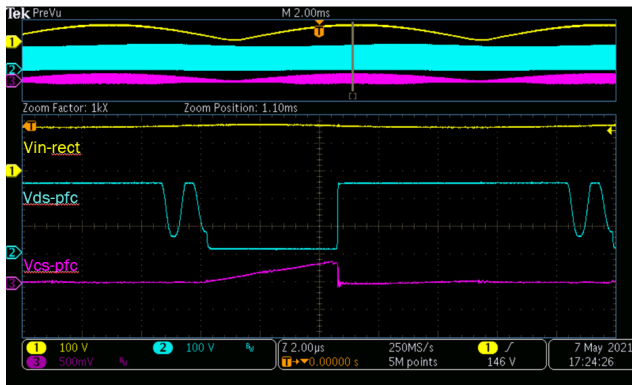


Figure 18. 115 Vac & 20 V 5 A
(CH1: Vin-rect, CH2: Vds-pfc, CH3: Vcs_pfc)

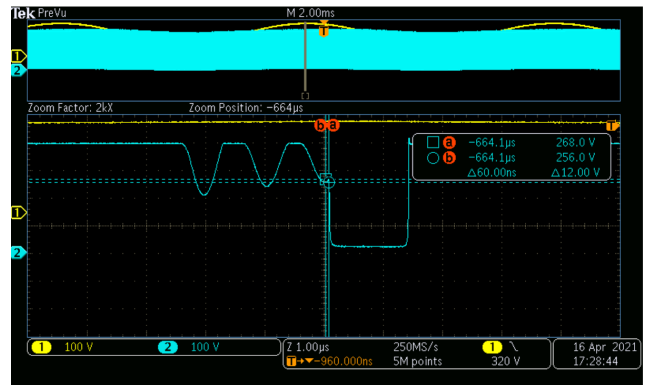


Figure 19. 230 Vac & 20 V 5 A
(CH1: Vin-rect, CH2: Vds-pfc)

INPUT CURRENT AT LL AND HL



Figure 20. 90 Vac & 20 V 5 A
(CH1: Vin-rect, CH3: lin)

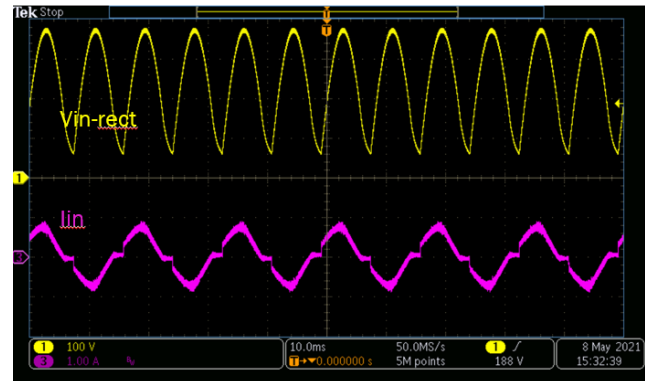


Figure 21. 64 Vac & 20 V 5 A
(CH1: Vin-rect, CH3: lin)

PFC OPERATION WAVEFORM AT LL AND HL

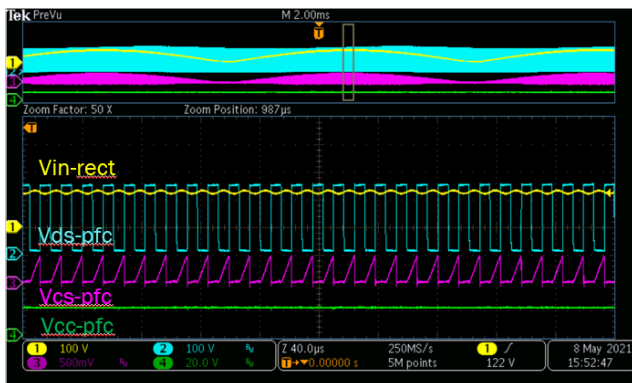


Figure 22. 90 Vac & 20 V 5 A
(CH1: Vin-rect, CH2: Vds-pfc, CH3: Vcs-pfc,
CH4: Vcc-pfc)

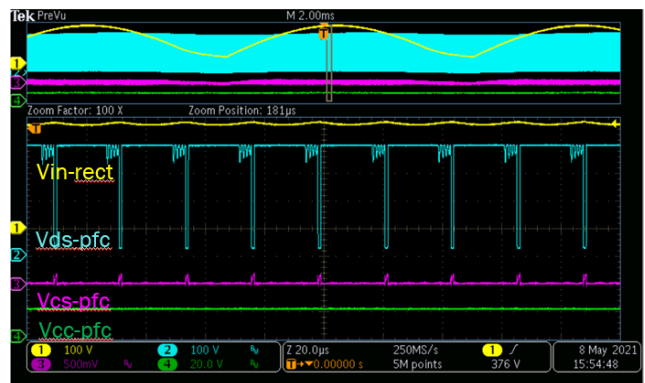


Figure 23. 264 Vac & 20 V 5 A
(CH1: Vin-rect, CH2: Vds-pfc, CH3: Vcs-pfc,
CH4: Vcc-pfc)

PFC LL TO HL AND HL TO LL CHANGE



Figure 24. 115 Vac to 230 Vac at 20 V 5 A
(CH1: Vin-rect, CH2: Vds-pfc, CH3: Vcs-pfc,
CH4: Vcc-pfc)

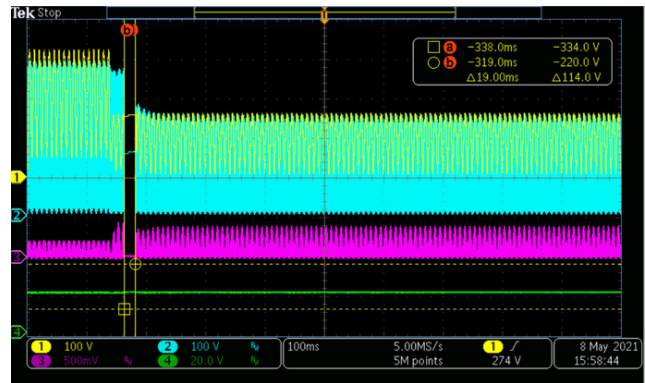


Figure 25. 230 Vac to 115 Vac at 20 V 5 A
(CH1: Vin-rect, CH2: Vds-pfc, CH3: Vcs-pfc,
CH4: Vcc-pfc)

PD VOLTAGE CHANGE

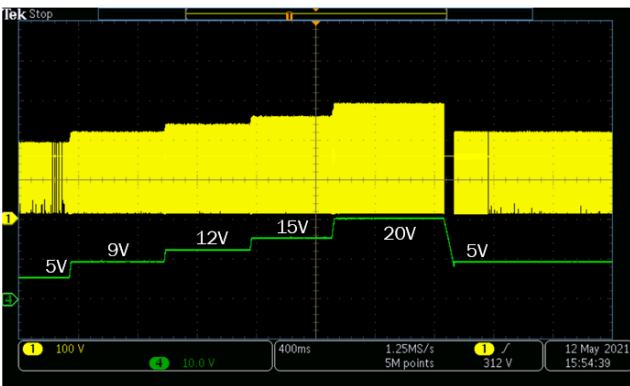


Figure 26. 115 Vac, No Load
(CH1: Vds, CH4: Vo)

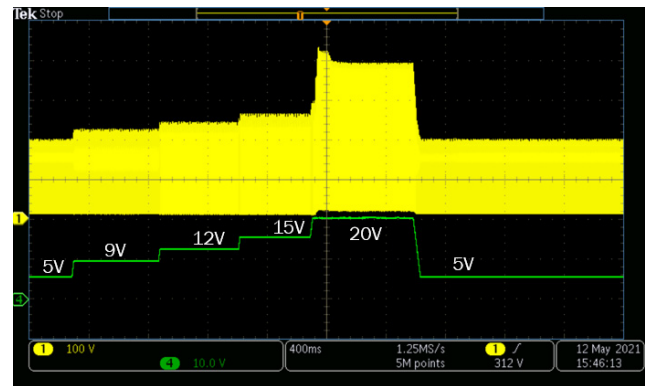


Figure 27. 115 Vac, 3 A Load
(CH1: Vds, CH4: Vo)

PRIMARY AND SEC. FET STRESS AT 264 Vac & 20 V 5 A

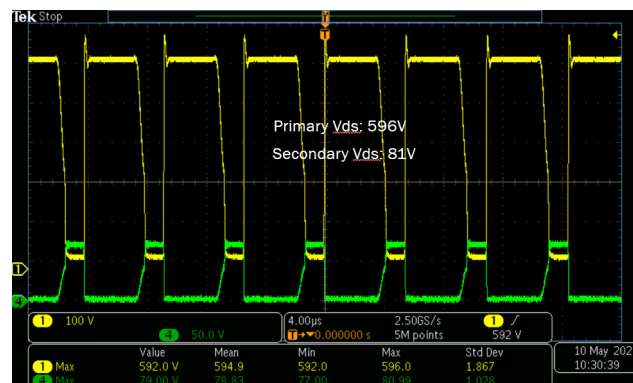


Figure 28. (CH1: Vds, CH4: Vds-sec)

SYN. DRIVE DURING LOAD TRANSITION AT 264 V

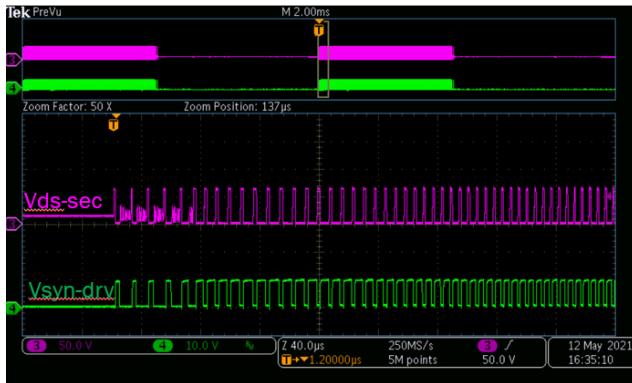


Figure 29. 264 Vac & 15 V, 0 to 3 A
(CH3: Vds-sec, CH4: Vsyn-driv)

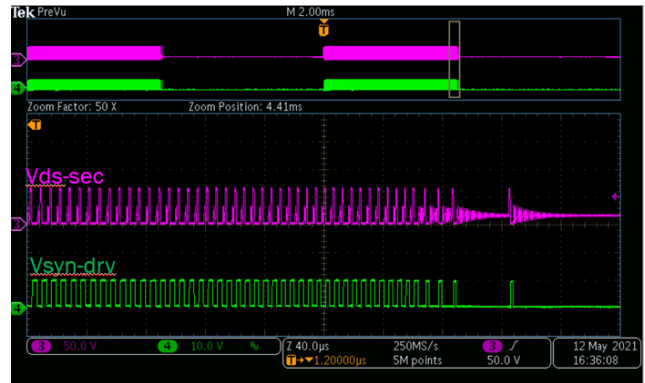


Figure 30. 264 Vac & 15 V, 3 A to 0
(CH3: Vds-sec, CH4: Vsyn-driv)

OUTPUT RIPPLE @ 90 Vac INPUT

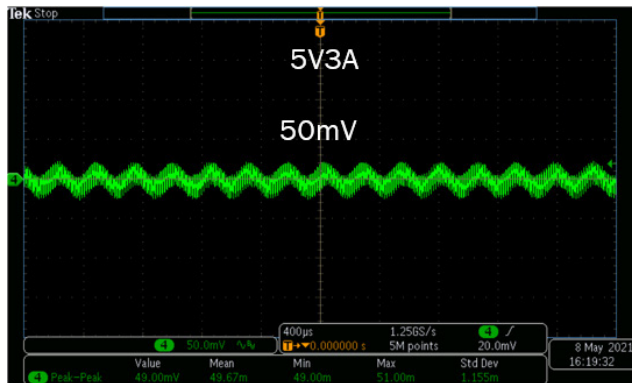


Figure 31. 5 V 3 A Output (CH4: Vo)

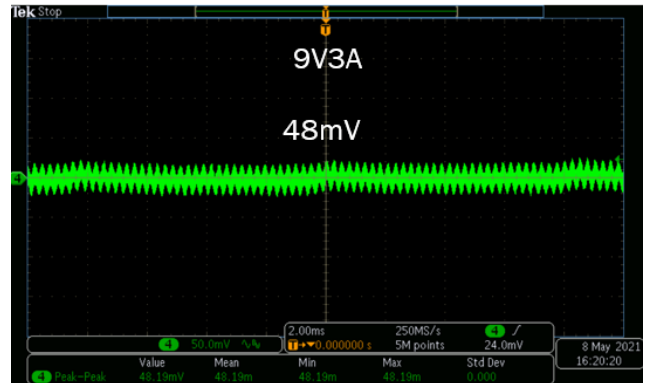


Figure 32. 9 V 3 A Output (CH4: Vo)

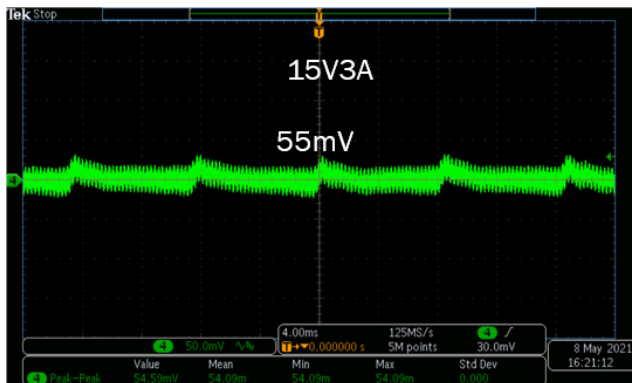


Figure 33. 15 V 3 A Output (CH4: Vo)

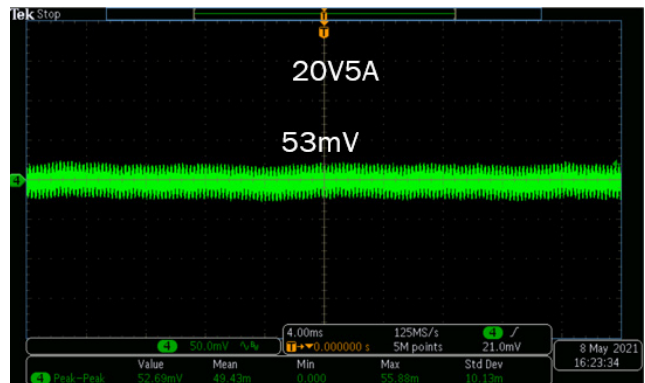


Figure 34. 20 V 5 A Output (CH4: Vo)

RIPPLE AT 90 Vac & 20 V 2.5 A (BEFORE PFC OPERATION)

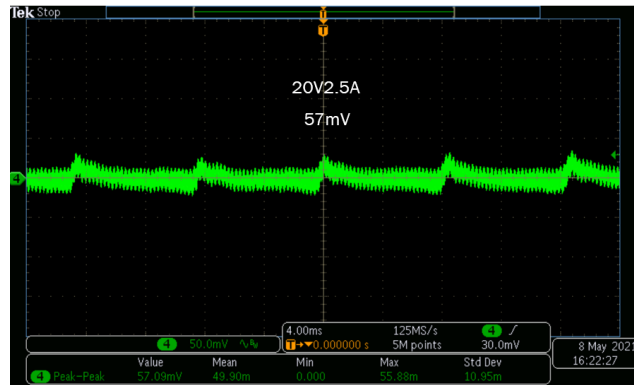


Figure 35. 20 V Output (CH4: Vo)

PWM OPERATION FREQUENCY AT FULL LOAD

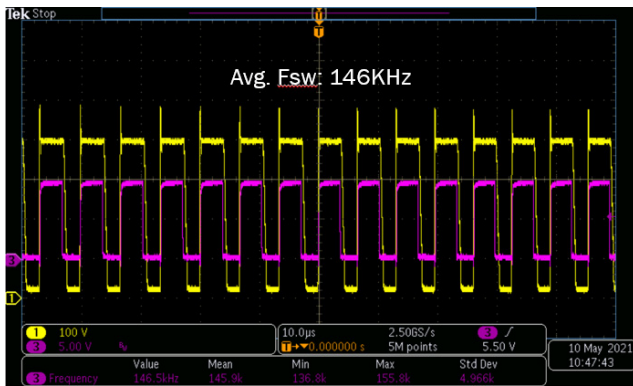


Figure 36. 90 Vac and 20 V 5 A
(CH1: Vds, CH3: Vsyn-drv)

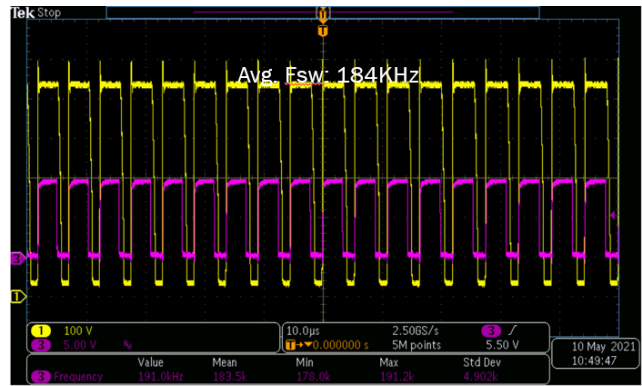


Figure 37. 264 Vac and 20 V 5 A
(CH1: Vds, CH3: Vsyn-drv)

NCP1343 TRANSITION LOAD FROM 0 – 5 A AT 90 Vac & 20 V

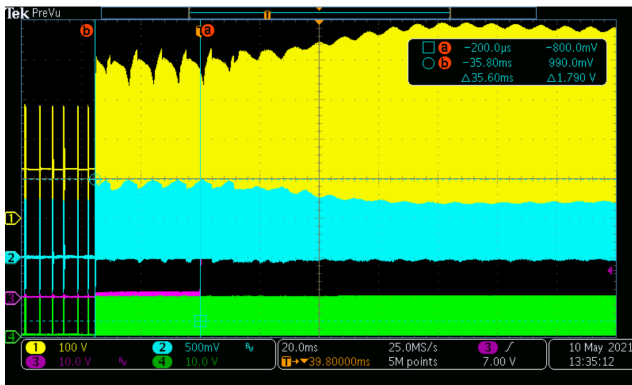


Figure 38. (CH1: Vds_pwm, CH: Vcs_pwm, CH3: Vcc_pfc, CH4: Vsyn_drv)



Figure 39. (CH1: Vds_pwm, CH: Vcs_pwm, CH3: Vcc_pfc, CH4: Vsyn_drv)



Figure 40.



Figure 41.

PRI. & SEC. Vds AND SYNCHRONOUS DRIVE WAVEFORM



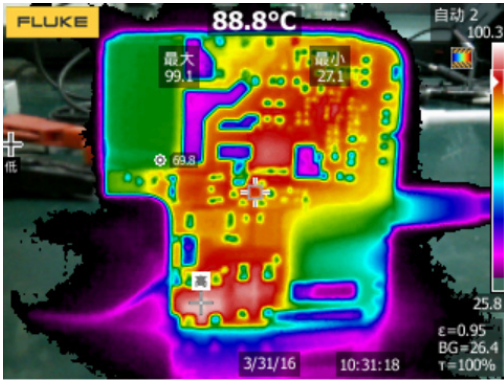
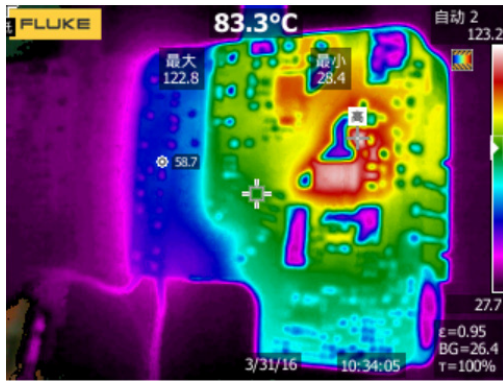
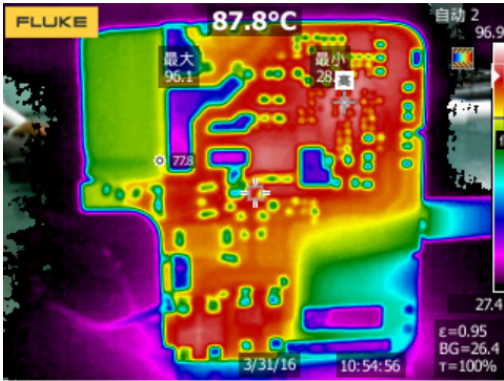
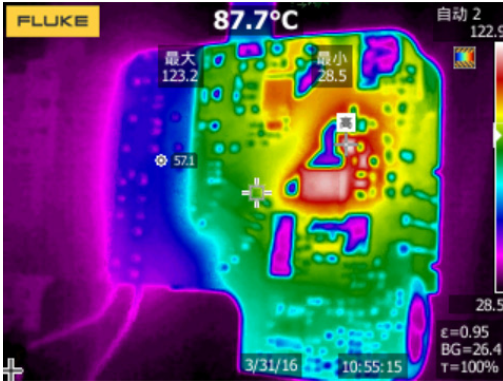
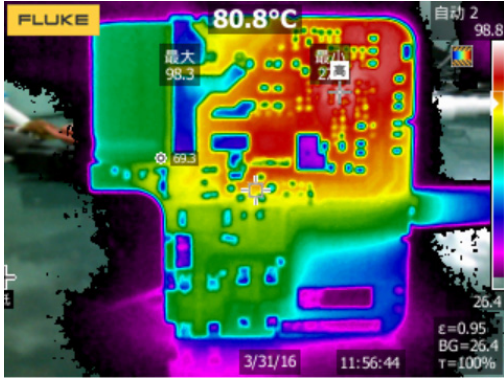
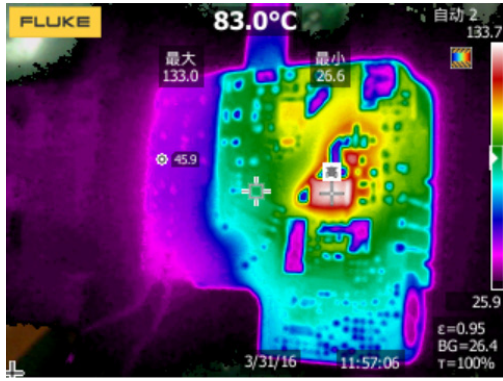
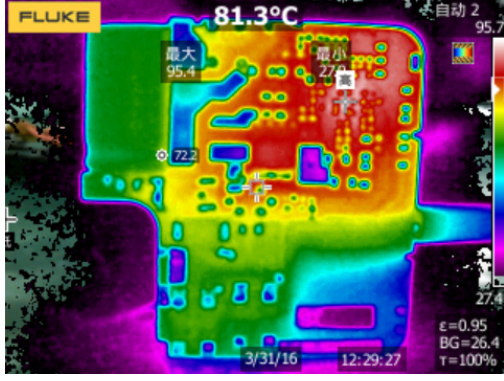
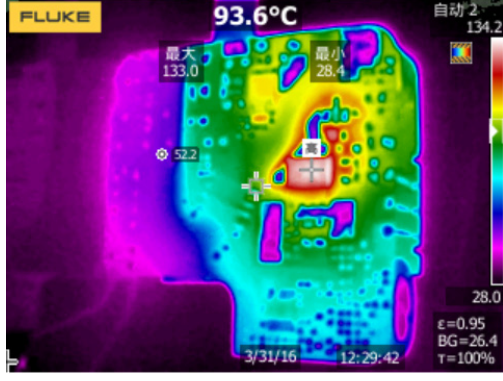
Figure 42. 90 Vac (CH1: Vds_sec, CH2: Vdrv)



Figure 43. 115 Vac (CH1: Vds_sec, CH2: Vdrv)

THERMAL IMAGE @ 20 V 3.25 A OUTPUT

Table 1.

Input	PFC Side	PWM Side
90 Vac		
115 Vac		
230 Vac		
264 Vac		

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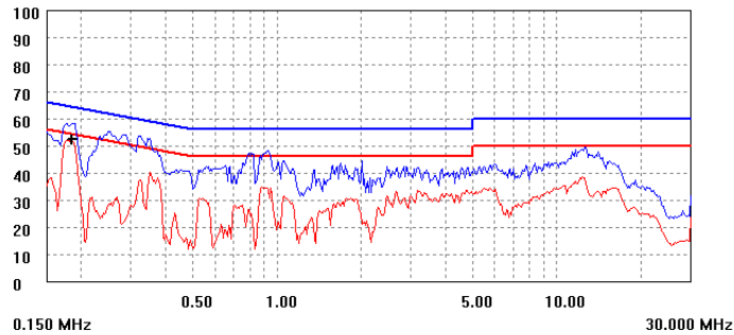
EMI

EMI Test at 230 Vac & Full Load

EMI TEST REPORT

Organization:	Operator:	EUT:
Place:	Time: 2021/5/11/17:32	Test equipment: KH3962
Detector: PK+AV	Test-time[ms]: 30	SN: 620883
Limit: EN55022B	Transducer(PK/AV): PK / AV	JZ: 2,15,665
Remark:		

Start[MHz]	End[MHz]	Step[MHz]
0.150	2.000	0.002
2.000	10.000	0.010
10.000	30.000	0.025



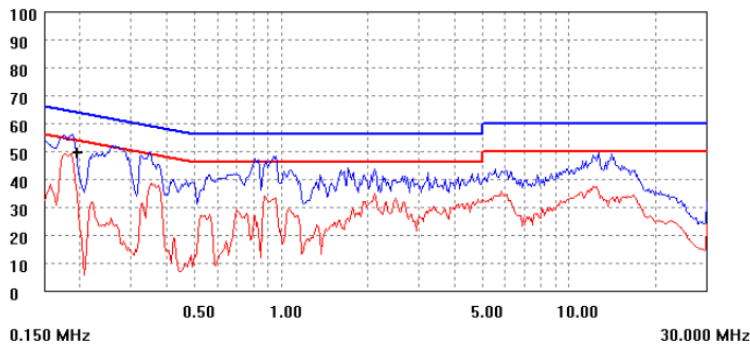
(AV)	freq[MHz]	lev[dBuV]	Lim[dBuV]	Δ (lev-Lim)
	0.185	52.3	54.3	-1.9

Figure 50. Line

EMI TEST REPORT

Organization:	Operator:	EUT:
Place:	Time: 2021/5/11/17:27	Test equipment: KH3962
Detector: PK+AV	Test-time[ms]: 30	SN: 620883
Limit: EN55022B	Transducer(PK/AV): PK / AV	JZ: 2,14,1438
Remark:		

Start[MHz]	End[MHz]	Step[MHz]
0.150	2.000	0.002
2.000	10.000	0.010
10.000	30.000	0.025



(AV)	freq[MHz]	lev[dBuV]	Lim[dBuV]	Δ (lev-Lim)
	0.195	49.5	53.8	-4.3

Figure 51. Neutral

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EMI Test at 115 Vac & Full Load

EMI TEST REPORT

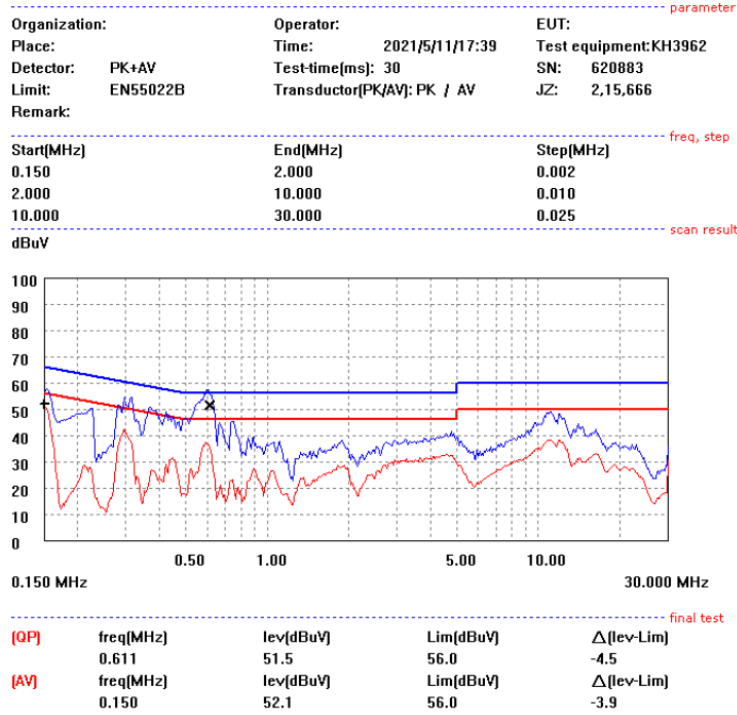


Figure 52. Line

EMI TEST REPORT

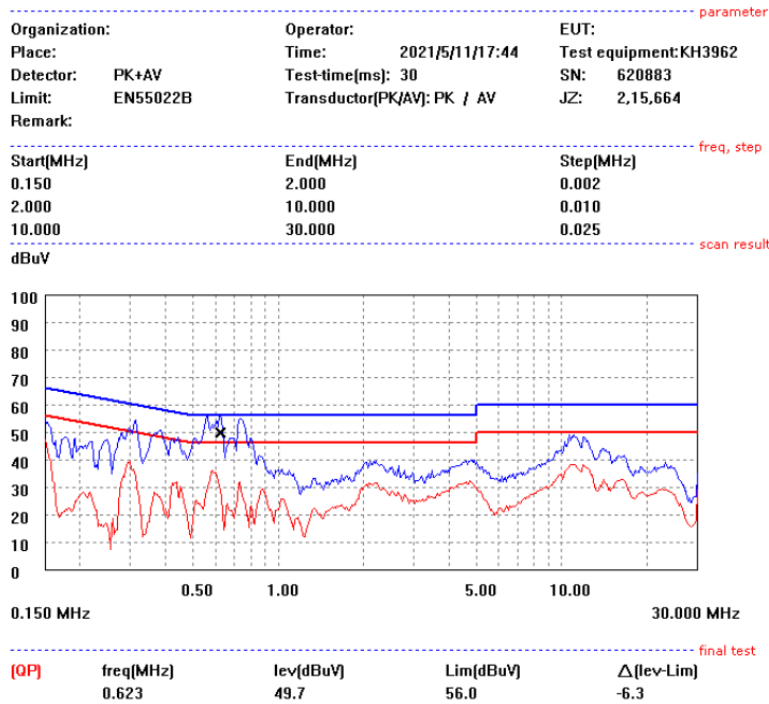


Figure 53. Neutral

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BOM

Table 2. BOM

Item	Qty	Reference	Type	Part Name	MFR	Value	Package	Description
1	1	Q9	NMOSFET	BSS123LT1G	SOT23	onsemi	0.2 A, 100 V	NMOSFET
2	1	C45	Ceramic Capacitor	Std	603	std	0.1 μ F	Capacitor, Ceramic, 50 V, 10%
3	1	C44	Ceramic Capacitor	/885012206120	603	Wurth	0.1 μ F, 100 V	Capacitor, Ceramic, 100 V, 10%
4	1	C37	Ceramic Capacitor	/885012206073	603	Wurth	0.22 μ F	Capacitor, Ceramic, 25 V, 10%
5	2	C1, C5	Film Capacitor	ECWFD2W684Q	THT, 10 mm, 13 mm x 6 mm x 12 mm	Panasonic	0.68 μ F, 450 V	Film capacitor
6	2	C9, C33	Ceramic Capacitor	/885012206077	603	Wurth	100 pF	Capacitor, Ceramic, 50 V, 10%
7	1	C8	Ceramic Capacitor	/885012206083	603	Wurth	102	Capacitor, Ceramic, 50 V, 10%
8	3	C26, C31, C47	Ceramic Capacitor	C3216X7T2W104K	1206	TDK	104, 450 V	Capacitor, Ceramic, SMD, 5%
9	1	C52	Ceramic Capacitor	/885012106018	603	Wurth	2.2 μ F, 16 V	Capacitor, Ceramic, 16 V, 10%
10	1	C12	Ceramic Capacitor	/885012006085	603	Wurth	1 nF, 100 V	Capacitor, Ceramic, SMD, 5%
11	4	C39, C49-50, C70	Ceramic Capacitor	/885012206076	603	Wurth	1 μ F, 25 V	Capacitor, Ceramic, 25 V, 10%
12	1	C27	Ceramic Capacitor	C2012X7R1E106K	805	TDK	10 μ F, 25 V	Capacitor, Ceramic, 25 V, 10%
13	1	C35	Ceramic Capacitor	/885012206085	603	Wurth	2.2 μ F	Capacitor, Ceramic, 50 V, 10%
14	1	C36	Ceramic Capacitor	/885012106018	603	Wurth	2.2 μ F	Capacitor, Ceramic, 16 V, 10%
15	1	C24	Ceramic Capacitor	/885012206079	603	Wurth	220 pF	Capacitor, Ceramic, 50 V, 10%
16	1	C25	X2 Capacitor	/890324024002	THT, 12.5 mm, 15 mm x 7 mm x 12 mm	Wurth	224, X2	X2 capacitor, Safety standard approved, 10%
17	1	C34	Ceramic Capacitor	/885012006053	603	Wurth	22 pF	Capacitor, Ceramic, 50 V, 10%
18	1	C41	Ceramic Capacitor	/885012206091	603	Wurth	22 nF	Capacitor, Ceramic, 50 V, 10%
19	2	C38, C69	Ceramic Capacitor	/885012206083	603	Wurth	330 pF	Capacitor, Ceramic, 50 V, 10%
20	1	C6	Ceramic Capacitor	Std	603	Std	36 pF	Capacitor, Ceramic, 50 V, 10%
21	1	C40	Ceramic Capacitor	/885012206092	603	Wurth	33nF	Capacitor, Ceramic, 50 V, 10%
22	4	C2, C4, C29, C43	Ceramic Capacitor	C1608X5R1E475K080AC	603	TDK	4.7 μ F, 25 V	Capacitor, Ceramic, 25 V, 10%
23	1	C3	Ceramic Capacitor	C3216C0G2J471J	1206	TDK	470 pF, 630 V	Capacitor, Ceramic, Chip, 5%
24	1	C10	Ceramic Capacitor	CD45-B2GA471K-NKA	Lead type	TDK	470 pF, Y1	HV Ceramic Capacitor, safety standard approved, 10%
25	1	C68	Ceramic Capacitor	std	603	Wurth	nc	Capacitor, Ceramic, 50 V, 10%
26	1	C20	Ceramic Capacitor	C2012X7S2A105K	805	TDK	nc	Capacitor, Ceramic, 100 V, 10%
27	1	C42	Ceramic Capacitor	Std	603	Wurth	nc	Capacitor, Ceramic, 50 V, 10%
28	2	D2, D4	Bridge rectifier	Z4GP40MH	Z4PAK	ZOWIE	4 A, 1000 V	Bridge Rectifier, 1000 V, 4 A
29	1	D9	Rectifier	S3J	SMC	onsemi	3 A, 600 V	General Rectifier
30	1	DNR	Varistor	820573011	TH	Wurth	10D471K	Varistor, 10D471K
31	1	D22	Switching diode	BAS21HT1G	SOD323	onsemi	0.2 A, 250 V	Switching diode, SMD
32	1	D7	Switching diode	BAS21HT1G	SOD323	onsemi	0.2 A, 250 V	Switching diode, SMD
33	2	D16, D24	Switching diode	BAT54HT1G	SOD323	onsemi	0.2 A, 30 V	Switching diode, SMD
34	1	D20	Switching diode	NSD350HT1G	SOD323	onsemi	0.2 A, 350 V	Switching diode, SMD
35	1	D5	General rectifier	4007	SOD123FL	std	0.8 A, 600 V	General Rectifier, 0.8 A, 600 V
36	2	D12-13	General rectifier	4007	SOD123FL	std	0.8 A, 600 V	General Rectifier, 0.8 A, 600 V
37	4	D8, D17-18, D23	Switching diode	BAS21HT1G	SOD323	onsemi	0.2 A, 250 V	Switching diode, SMD
38	1	FB2	Ferrite bead	742792511	1812	Wurth	120 Ω @ 100 M, 3 A	120 Ω @ 100 MHz
39	1	FB1	Ferrite bead	PZ3225D601-3R0TFONL	1210	Shunlord	600 Ω @ 100 M, 3 A	600 Ω @ 100 MHz
40	1	L1	Common filter	Custom	TH type	Customed	30 μ H	T type, 8*4*3 NiZn core
41	1	L2	Common filter	Custom	TH type	Customed	18 mH	CM Filter, T14*8*7 MnZn core
42	1	F1	Fuse	20T-016H	Axial lead	Hollyfuse	3.15 A, 250 Vac	Micro Fuse, 1.6 A/250 V

Table 2. BOM (continued)

Item	Qty	Reference	Type	Part Name	MFR	Value	Package	Description
43	1	Q7	NPN Transistor	MMBT3904LT1G	SOT23	onsemi		General NPN Transistor, SMD
44	1	Q13	PNP Transistor	MMBT3906LT1G	SOT23	onsemi		General PNP Transistor, SMD
45	1	D3	Ultrafast Rectifier	MURD550PFG	DPAK	onsemi	5 A, 520 V	Ultrafast Rectifier, 5 A, 520 V
46	1	U5	PFC controller	NCP1623ASNT1G	TSOP6	onsemi		2 stage Follower/Boost PFC controller
47	1	U3	Syn. rectified controller	NCP4307FASNT1G	TSOP6	onsemi		Syn. Controller
48	1	U1	PWM controller	NCP1343AMDCDBD1R2G	SO9	onsemi		2x PEM CCM/QR controller
49	1	NTC1	NTC	SDNT1608X104J4250HTF	603	Shunlord	100 k	NTC, 0603, replaced by 100 kΩ resistor
50	1	NTC2-3	NTC	SDNT1608X104J4250HTF	603	Shunlord	nc	NTC, 0603, no connect
51	2	U4, U11	Optical coupler	FODM1009	LSOP4	onsemi		optical coupler, standard SOP package
52	1	L3	Toroidal Line Choke	7447021	TH type	Würth	100 μH	Toroidal Line Choke, 15.8 x 8.5, 2.5 A
53	1	L6	SMD Inductor	MCL1608S4R7MT	603	Shunlord	4.7 μH	
54	1	R11	Resistor	Std	603	Std	0 Ω	Resistor, Chip, 1/10 W, 1%
55	2	R48, R57	Resistor	Std	603	Std	0 Ω	Resistor, Chip, 1/10 W, 1%
56	1	R61	Resistor	Std	603	Std	1 Ω	Resistor, Chip, 1/10 W, 1%
57	3	R13, R32, R49	Resistor	Std	603	Std	100 kΩ	Resistor, Chip, 1/10 W, 1%
58	1	R21	Resistor	Std	603	Std	10 kΩ	Resistor, Chip, 1/10 W, 1%
59	4	R23, R38, R46, R66	Resistor	Std	603	Std	10 Ω	Resistor, Chip, 1/10 W, 1%
60	3	R3, R34, R36	Resistor	Std	603	Std	1 kΩ	Resistor, Chip, 1/10 W, 1%
61	1	R8	Resistor	Std	603	Std	2.4 kΩ	Resistor, Chip, 1/10 W, 1%
62	1	R60	Resistor	Std	603	Std	200 Ω	Resistor, Chip, 1/10 W, 1%
63	1	R33	Resistor	Std	603	Std	200 kΩ	Resistor, Chip, 1/10 W, 1%
64	1	R65	Resistor	Std	805	Std	30 Ω	Resistor, Chip, 1/8 W, 1%
65	3	R39, R52, R56	Resistor	Std	603	Std	22 kΩ	Resistor, Chip, 1/10 W, 1%
66	1	R9	Resistor	Std	603	Std	2 kΩ	Resistor, Chip, 1/10 W, 1%
67	2	R27, R53	Resistor	Std	603	Std	270 kΩ	Resistor, Chip, 1/10 W, 1%
68	1	R43	Resistor	Std	603	Std	30 kΩ	Resistor, Chip, 1/10 W, 1%
69	1	R63	Resistor	Std	603	Std	300 kΩ	Resistor, Chip, 1/10 W, 1%
70	1	R16	Resistor	Std	603	Std	36 kΩ	Resistor, Chip, 1/10 W, 1%
71	1	R20	Resistor	Std	603	Std	390 kΩ	Resistor, Chip, 1/10 W, 1%
72	2	R26, R28	Resistor	Std	603	Std	4.7 Ω	Resistor, Chip, 1/10 W, 1%
73	1	R30	Resistor	Std	603	Std	5.1 kΩ	Resistor, Chip, 1/10 W, 1%
74	2	R47, R54	Resistor	Std	603	Std	47 Ω	Resistor, Chip, 1/10 W, 1%
75	1	R28	Resistor	Std	603	Std	47 kΩ	Resistor, Chip, 1/10 W, 1%
76	1	R22	Resistor	Std	603	Std	510 Ω	Resistor, Chip, 1/10 W, 1%
77	1	R29	Resistor	Std	603	Std	nc	Resistor, Chip, 1/10 W, 1%,
78	2	R50-51	Resistor	ERJ8BQFR24V	1206	Panasonic	0,24 Ω	Resistor, Chip, 1/2 W, 1%
79	2	R4-5	Resistor	ERJ8BQFR56V	1206	Panasonic	0,56 Ω	Resistor, Chip, 1/2 W, 1%
80	1	R40	Resistor	std	1206	Std	1.6 MΩ	Resistor, Chip, 1/4 W, 1%
81	2	R1-2	Resistor	Std	1206	Std	120 Ω	Resistor, Chip, 1/4 W, 1%
82	2	R7, R58	Resistor	Std	1206	Std	2.4 MΩ	Resistor, Chip, 1/4 W, 1%
83	2	R31, R35	Resistor	Std	1206	Std	2.7 kΩ	Resistor, Chip, 1/4 W, 1%
84	1	R12	Resistor	Std	1206	Std	22 Ω	Resistor, Chip, 1/4 W, 1%
85	2	R41-42	Resistor	Std	1206	Std	2 MΩ	Resistor, Chip, 1/4 W, 1%
86	1	R45	Resistor	Std	1206	Std	390 kΩ	Resistor, Chip, 1/4 W, 1%

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Table 2. BOM (continued)

Item	Qty	Reference	Type	Part Name	MFR	Value	Package	Description
87	1	R25	Resistor	ERJ8BQFR005V	1206	Panasonic	5 mΩ	Resistor, Chip, 1/2 W, 1%
88	1	T2	Transformer	Customed	TH type	Custom	see specification	RM8, Ferroxcube 3C95, 6 Pin Bobbin
89	1	T1	PFC Inductor	Customed	TH type	Custom	200 μH	RM8, Ferroxcube 3C95 core, 6 Pin Bobbin
90	1	C46	Electrolytic capacitor	KF Series	6.3 mm x 11 mm	CapXon	22 μF, 100 V	size: 6.3 mm x 11 mm
91	3	C13–14, C48	Electrolytic solid capacitor	PS681M025F080P	8 mm x 14 mm	CapXon	680 μF, 25 V	size: 8 mm x 14 mm
92	1	C32	Electrolytic electrolytic capacitor	KL680M450J300A00H	18 mm x 30 mm	CapXon	68 μF, 450 V	size: 18 mm x 30 mm
93	1	Q1	MOSFET	FDMS86180	SO8FL	onsemi		MOSFET, NChan, 100 V
94	1	Q3	MOSFET	FCMT250N65S3	Power88	onsemi		MOSFET, NChan, 650 V
95	1	Q2	MOSFET	FCMT199N60	Power88	onsemi		MOSFET, NChan, 600 V
96	1	Q8	MOSFET	NTTFS4C02NT1G	u8FL	onsemi		MOSFET, NChan, 3.4 mΩ
97	1	J1	USB Type C connector	CUS31738616001	SMD	CSCONN		Type C connector, SMT
98	1	U10	PD Controller	FUSB15101	DFN4X4	onsemi		PD protocol controller
99	1	ZD2	Zener	MM3Z13VT1G	SOD323	onsemi	13 V	GENERIC ZENER-DIODE
100	1	ZD1	Zener	MM3Z18VT1G	SOD323	onsemi	18 V	GENERIC ZENER-DIODE
101	4	ESD1–4	ESD	SD05T1G	SOD323	onsemi	5 V	ESD protection device

REFERENCES

onsemi datasheet for NCP1623, NCP1343, NCP4307, FUSB15101, FCMT199N60, FCMT250N65, FDMS86180, NTTFS4C02

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